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<u>Diodes Incorporated</u> 74AHC1G08SE-7

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74AHC1G08

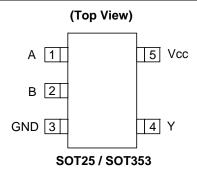
SINGLE 2 INPUT POSITIVE AND GATE

Description

The 74AHC1G08 is a single 2-input positive AND gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

$$Y = A \bullet B$$
 or $Y = \overline{A} + \overline{B}$

Pin Assignments



Features

- Supply Voltage Range from 2.0V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
 - o Exceeds 200-V Machine Model (A115-A)
 - o Exceeds 2000-V Human Body Model (A114-A)
 - o Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

Applications

- General Purpose Logic
- Wide array of products such as:
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.





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Pin Descriptions

Pin Name	Pin NO.	Description	
А	1	Data Input	
В	2	Data Input	
GND	3	Ground	
Υ	4	Data Output	
Vcc	5	Supply Voltage	

Logic Diagram



Function Table

Inpi	Output	
Α	В	Υ
Н	Н	Н
L	Х	L
X	L	L





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Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-20	mA
I _{OK}	Output Clamp Current (V _O < 0 or V _O > V _{CC})	±20	mA
Io	Continuous output current (V _O = 0 to V _{CC})	±25	mA
I _{CC}	Continuous current through V _{CC}	50	mA
I _{GND}	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol	P	arameter	Min	Max	Unit
V _{CC}	Operating Voltage		2	5.5	V
		$V_{CC} = 2V$	1.5		
V_{IH}	High-level Input Voltage	$V_{CC} = 3V$	2.1		V
		$V_{CC} = 5.5V$	3.85		
		V _{CC} = 2V		0.5	
V_{IL}	•	$V_{CC} = 3V$		0.9	V
		$V_{CC} = 5.5V$		1.65	
VI	Input Voltage	<u> </u>	0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		$V_{CC} = 2V$		-50	uA
I _{OH}	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-4	^
	Low-level input voltage Input Voltage Output Voltage High-level output current Low-level output current Input transition rise or fall rate	$V_{CC} = 5V \pm 0.5V$		-8	mA
		$V_{CC} = 2V$		50	uA
I_{OL}	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4	A
		$V_{CC} = 3V$		8	mA
A+/A\/	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	//
Δt/ΔV		$V_{CC} = 5V \pm 0.5V$		20	ns/V
T _A	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at $V_{\mbox{CC}}$ or Ground.





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Electrical Characteristics

Comple of	Danamatan	Took Conditions	V		25°C		-40°C t	o 85°C	-40°C to	o 125ºC	l læit
Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Min	Max	Unit
			2V	1.9	2		1.9		1.9		
		$I_{OH} = -50\mu A$	3V	2.9	3		2.9		2.9		
V _{OH}	High Level		4.5V	4.4	4.5		4.4		4.4		V
	Output Voltage	$I_{OH} = -4mA$	3V	2.58			2.48		2.40		
		$I_{OH} = -8mA$	4.5V	3.94			3.8		3.70		
			2V			0.1		0.1		0.1	
		$I_{OL} = 50\mu A$	3V			0.1		0.1		0.1	
V_{OL}	High-level Input		4.5V			0.1		0.1		0.1	V
	Voltage	$I_{OL} = 4mA$	3V			0.36		0.44		0.55	
		$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	
II	Input Current	V _I = 5.5 V or GND	0 to 5.5V			± 0.1		± 1		± 2	μΑ
I _{CC}	Supply Current	$V_I = 5.5V$ or GND $I_O=0$	5.5V			1		10		40	μΑ
C _I	Input Capacitance	$V_I = V_{CC} - \text{ or GND}$	5.5V		2.0	10		10		10	pF
0	Thermal Resistance	SOT25	(Note 4)		195						°C/W
θ _{JA}	Junction-to- Ambient	SOT353	(Note 4)		430						C/VV
Α	Thermal Resistance	SOT25	(Note 4)		58						°C/W
θ _{JC}	Junction-to- Case	SOT353	(Note 4)		155						C/VV

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

Switching Characteristics

$V_{CC} = 3.3V \pm 0.3$ (see Figure 1)

Doromotor	From	ТО			25°C		-40°C t	o 85ºC	-40°C to	o 125ºC	Unit
Parameter (Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Offic	
4	A or D	V	C _L =15pF	0.6	4.6	8.8	0.6	10.5	0.6	12.0	ns
t _{pd}	A or B	Y	C _L =50pF	0.6	6.5	12.3	0.6	14.0	0.6	16.0	ns

$V_{CC} = 5V \pm 0.5V$ (see Figure 1)

	Davamatar	From	TO			25°C		-40°C t	o 85ºC	-40°C to	o 125ºC	Unit
•	Parameter (Input) (OUTPUT	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit	
	4	Λ o π D		C _L =15pF	0.6	3.2	5.9	0.6	7.0	0.6	8.0	ns
	^L pd	A or B	ř	C _L =50pF	0.6	4.6	7.9	0.6	9.0	0.6	10.5	ns





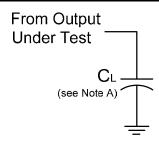
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Operating Characteristics

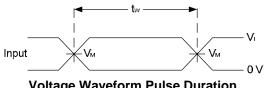
 $T_A = 25$ °C

	Parameter	Test Conditions	V _{CC} = 5V Typ.	Unit
C _{pd}	Power dissipation capacitance	f = 1 MHz No Load	12	pF

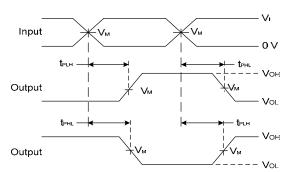
Parameter Measurement Information



V	In	puts	V	C
V _{CC}	VI	t _r /t _f	V _M	CL
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	15pF
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	15pF
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	50pF
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	50pF



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}.





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Ordering Information

T4AHC1G 08 XX - 7

Logic Device Function Package Packing

74 : Logic Prefix 08 : 2-Input W5 : SOT25 7 : Tape & Reel

AHC: 2 to 5.5V Family 1G: One gate

	Davisa	Package	Packaging	7" Tape a	and Reel
	Device	Code	(Note 5)	Quantity	Part Number Suffix
Pb ,	74AHC1G08W5-7	W5	SOT25	3000/Tape & Reel	-7
Pb,	74AHC1G08SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

AND -Gate

Marking Information

(Top View)

XX Y W X

XX : Identification code

Y: Year 0~9

<u>W</u>: Week: A~Z: 1~26 week;

SE: SOT353

a~z: 27~52 week; z represents

52 and 53 week

 \underline{X} : A $^{\sim}$ Z: Internal code

Part Number	Package	Identification Code
74AHC1G08W5	SOT25	YU
74AHC1G08SE	SOT353	YU

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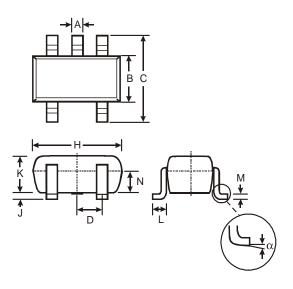


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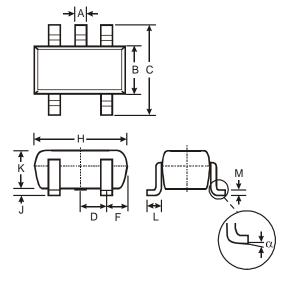
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



	SOT	725						
Dim	Dim Min Max Typ							
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D		_	0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
K	1.00	1.30	1.10					
L	0.35	0.55	0.40					
M	0.10	0.20	0.15					
N	0.70	0.80	0.75					
α	0°	8°	_					
All D	imensi	ons in	mm					

(2) Package Type: SOT353



SOT353		
Dim	Min	Max
Α	0.10	0.30
В	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
Н	1.80	2.20
7	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

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